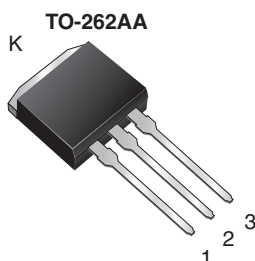
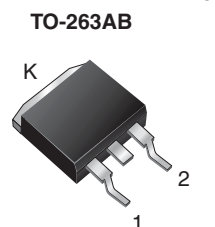
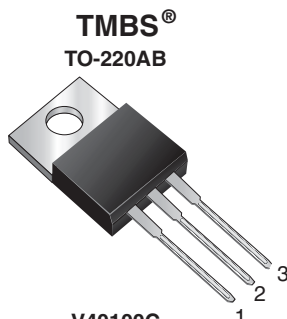




Dual High-Voltage Trench MOS barrier Schottky Rectifier

Ultra Low $V_F = 0.38\text{ V}$ at $I_F = 5\text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, TO-263AB and TO-262AA package)
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 20 A
V_{RRM}	100 V
I_{FSM}	250 A
V_F at $I_F = 20\text{ A}$	0.61 V
T_J max.	150 °C

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V40100C	VB40100C	VI40100C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	100			V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	40			A
		20			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	250			A
Non-repetitive avalanche energy at $T_J = 25\text{ °C}$, $L = 90\text{ mH}$ per diode	E_{AS}	230			mJ
Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$, 1 kHz, $T_J = 38\text{ °C} \pm 2\text{ °C}$ per diode	I_{RRM}	1.0			A
Voltage rate of change (rated V_R)	dV/dt	10 000			V/ μs
Operating junction and storage temperature range	T_J, T_{STG}	- 40 to + 150			°C



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage ⁽²⁾	I _R = 1.0 mA	T _A = 25 °C	V _{BR}	100 (minimum)	-	V
	I _R = 10 mA			105 (minimum)	-	
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 5 A	T _A = 25 °C	V _F	0.47	-	V
	I _F = 10 A			0.54	-	
	I _F = 20 A			0.67	0.73	
	I _F = 5 A	T _A = 125 °C		0.38	-	
	I _F = 10 A			0.45	-	
	I _F = 20 A			0.61	0.67	
Reverse current at rated V _R per diode ⁽²⁾	V _R = 70 V	T _A = 25 °C	I _R	9	-	μA
		T _A = 125 °C		10	-	mA
	V _R = 100 V	T _A = 25 °C		-	1000	μA
		T _A = 125 °C		21	45	mA

Notes(1) Pulse test: 300 μs pulse width, 1 % duty cycle(2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	V40100C	VB40100C	VI40100C	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	2.0	2.0	2.0	$^\circ\text{C/W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	V40100C-E3/4W	1.85	4W	50/tube	Tube
TO-263AB	VB40100C-E3/4W	1.39	4W	50/tube	Tube
TO-263AB	VB40100C-E3/8W	1.39	8W	800/reel	Tube
TO-262AA	VI40100C-M3/4W	1.46	4W	50/tube	Tube

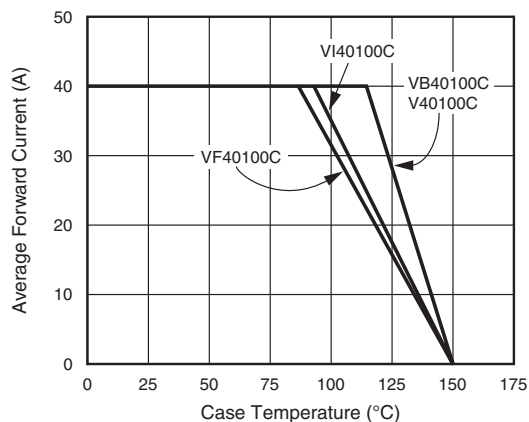
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 - Forward Current Derating Curve

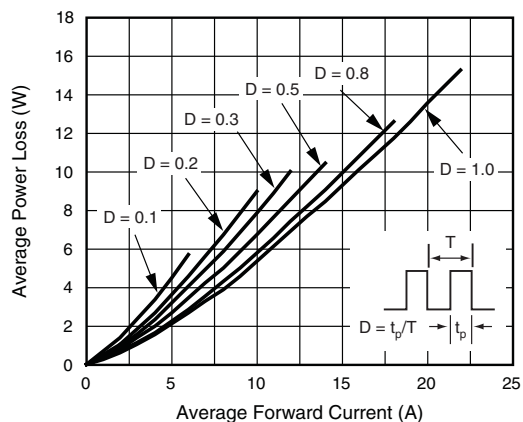


Fig. 2 - Forward Power Loss Characteristics Per Diode

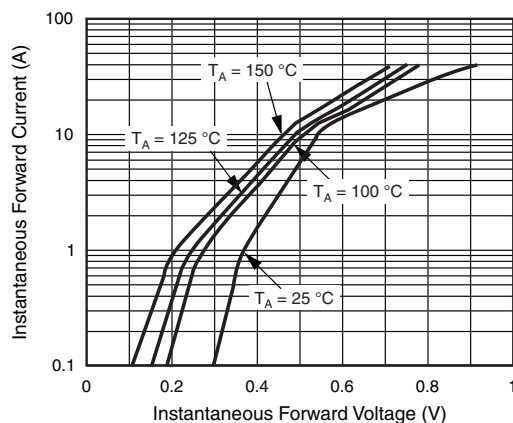


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

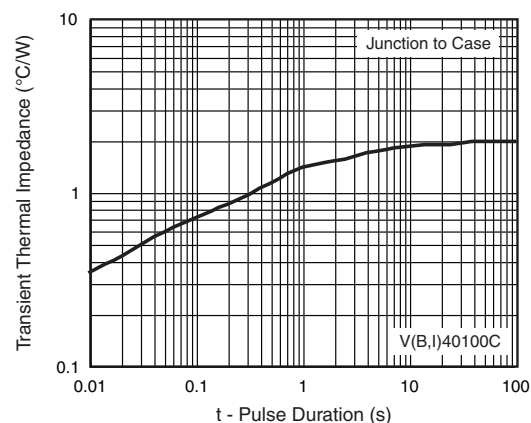


Fig. 6 - Typical Transient Thermal Impedance Per Diode

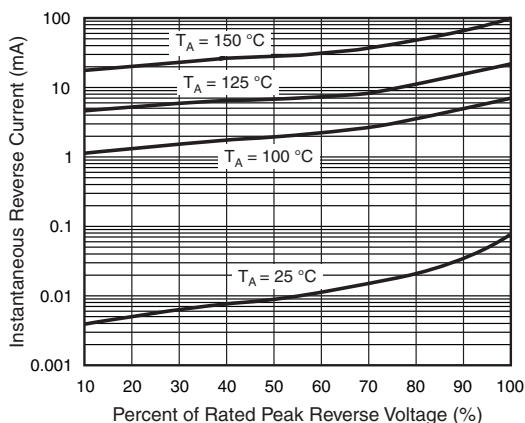


Fig. 4 - Typical Reverse Characteristics Per Diode

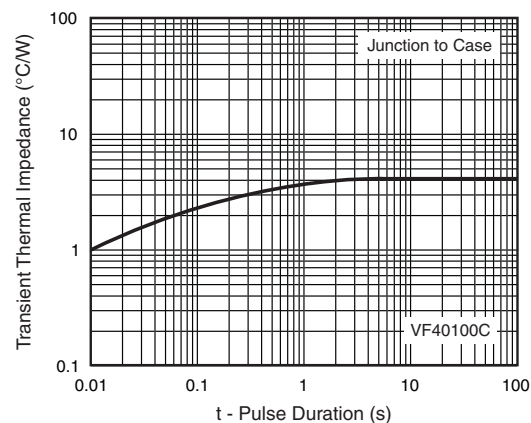


Fig. 7 - Typical Transient Thermal Impedance Per Diode

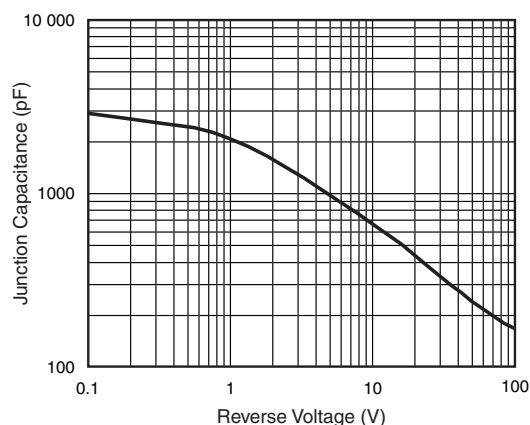
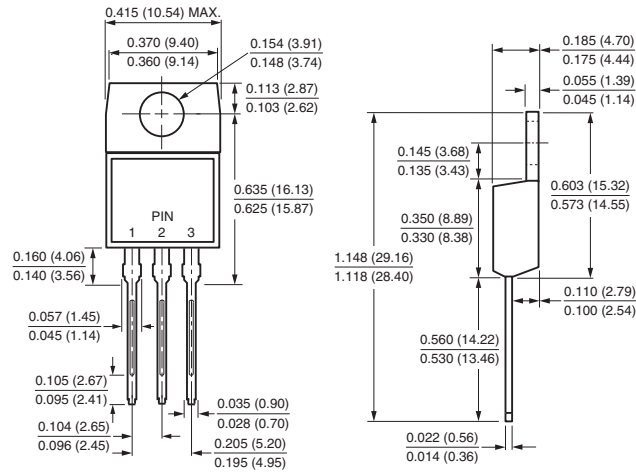


Fig. 5 - Typical Junction Capacitance Per Diode

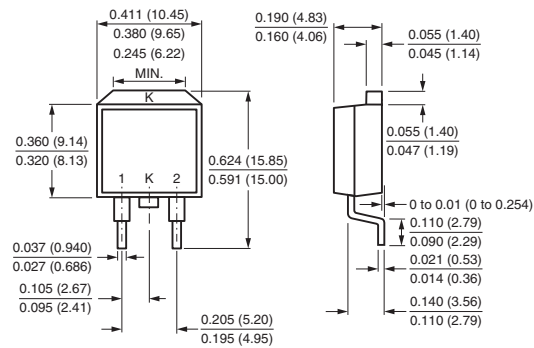


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

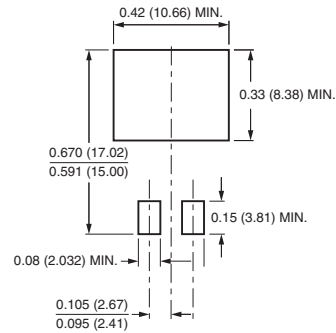
TO-220AB



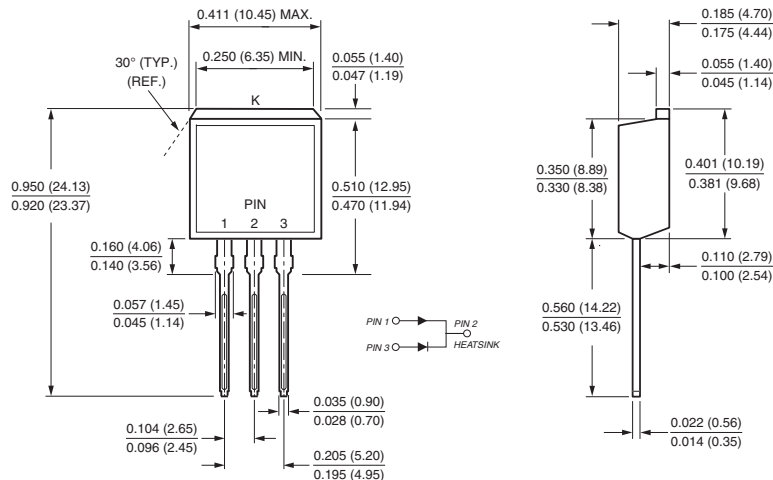
TO-263AB



Mounting Pad Layout



TO-262AA





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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9